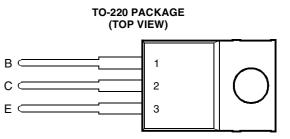
# BOURNS®

- Rugged Triple-Diffused Planar Construction
- 100 W at 25°C Case Temperature
- 5 A Continuous Collector Current



Pin 2 is in electrical contact with the mounting base.

MDTRACA

## absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT	
Collector-base voltage ( $I_E = 0$ )	V <sub>CBO</sub>	850	V	
Collector-emitter voltage (V <sub>BE</sub> = 0)	V <sub>CES</sub>	850	V	
Collector-emitter voltage ( $I_B = 0$ )	V <sub>CEO</sub>	400	V	
Emitter-base voltage	V <sub>EBO</sub>	10	V	
Continuous collector current	ι <sub>c</sub>	5	A	
Peak collector current (see Note 1)	I <sub>CM</sub>	10	A	
Continuous device dissipation at (or below) 25°C case temperature	P <sub>tot</sub>	100	W	
Operating junction temperature range	Тj	-65 to +150	°C	
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C	

NOTE 1: This value applies for  $t_p \le 10$  ms, duty cycle  $\le 2\%$ .

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# BUT11 NPN SILICON POWER TRANSISTOR



## electrical characteristics at 25°C case temperature (unless otherwise noted)

I	TEST CONDITIONS				MIN	ТҮР	MAX	UNIT	
V <sub>CEO(sus)</sub>	Collector-emitter sustaining voltage	I <sub>C</sub> =	0.1 A	L = 25 mH	(see Note 2)	400			V
I <sub>CES</sub>	Collector-emitter cut-off current	V <sub>CE</sub> = V <sub>CE</sub> =		V <sub>BE</sub> = 0 V <sub>BE</sub> = 0	T <sub>C</sub> = 125°C			50 500	μΑ
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =	10 V	$I_{\rm C} = 0$				1	mA
h <sub>FE</sub>	Forward current transfer ratio	V <sub>CE</sub> =	5 V	I <sub>C</sub> = 0.5 A	(see Notes 3 and 4)	20		60	
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> =	0.6 A	I <sub>C</sub> = 3 A	(see Notes 3 and 4)			1.5	V
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	I <sub>B</sub> =	0.6 A	I <sub>C</sub> = 3 A	(see Notes 3 and 4)			1.3	V
f <sub>t</sub>	Current gain bandwidth product	V <sub>CE</sub> =	10 V	I <sub>C</sub> = 0.5 A	f = 1 MHz		12		MHz
C <sub>ob</sub>	Output capacitance	V <sub>CB</sub> =	20 V	I <sub>E</sub> = 0	f = 0.1 MHz		110		pF

NOTES: 2. Inductive loop switching measurement.

3. These parameters must be measured using pulse techniques,  $t_p = 300 \ \mu$ s, duty cycle  $\le 2\%$ .

4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

## thermal characteristics

PARAMETER			MAX	UNIT
R <sub>0JC</sub> Junction to case thermal resistance			1.25	°C/W

## inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS <sup>†</sup>				ТҮР	MAX	UNIT
t <sub>sv</sub>	Voltage storage time	I <sub>C</sub> = 3 A	$I_{B(on)} = 0.6A$	$V_{BE(off)} = -5 V$			1.4	μs
t <sub>fi</sub>	Current fall time	V <sub>CC</sub> = 50 V	(see Figures 1 and 2)				150	ns
t <sub>sv</sub>	Voltage storage time	I <sub>C</sub> = 3 A	$I_{B(on)} = 0.6A$	$V_{BE(off)} = -5 V$			1.5	μs
t <sub>fi</sub>	Current fall time	V <sub>CC</sub> = 50 V	$T_{C} = 100^{\circ}C$				300	ns

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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# PARAMETER MEASUREMENT INFORMATION

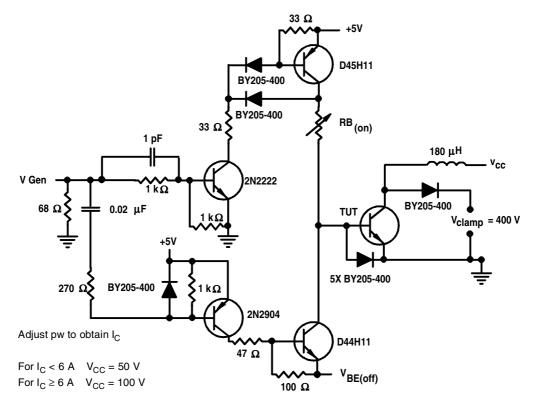
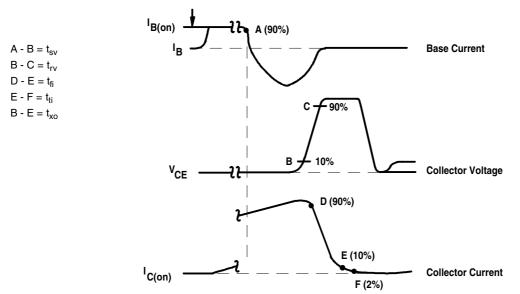
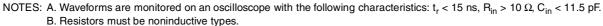


Figure 1. Inductive-Load Switching Test Circuit





#### Figure 2. Inductive-Load Switching Waveforms

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# MAXIMUM SAFE OPERATING REGIONS

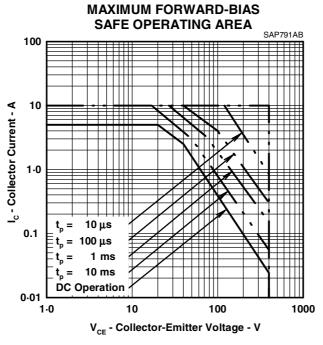


Figure 3.



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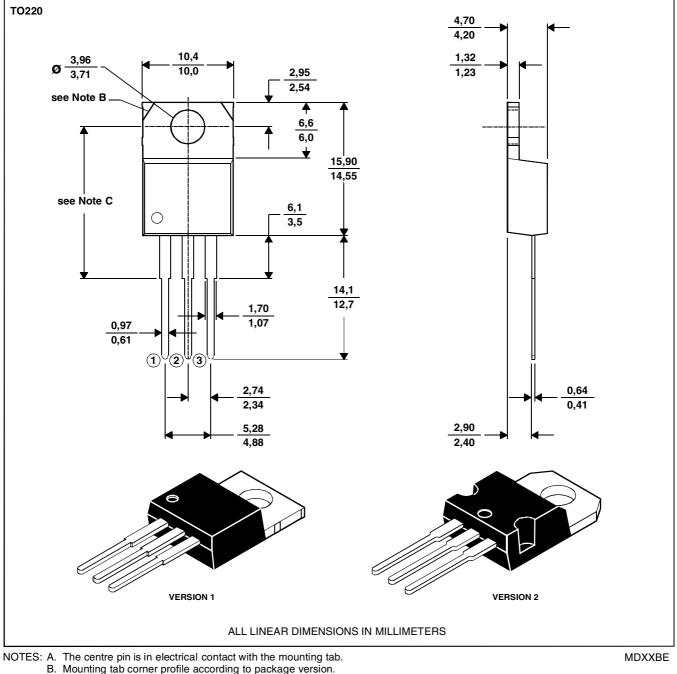


## **MECHANICAL DATA**

# TO-220

# 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

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